AT-213-PIN



Digital Attenuator 15.0 dB, 4-Bit, TTL Driver, DC-3.0 GHz

Rev. V5

Features

- Attenuation: 1 dB steps to 15 dB
- Temperature Stability: ± 0.18 dB from –55°C to +85°C Typical
- Low DC Power Consumption
- Hermetic Surface Mount Package
- Integral TTL Driver
- 50 Ohms Nominal Impedance
- Lead-Free CR-11 Package
- 260°C Reflow Compatible
- RoHS* Compliant

Description

M/A-COM's AT-213-PIN is a 4-bit, 1 dB step digital attenuator in a hermetically sealed ceramic 16-lead surface mount package. The AT-213-PIN is ideally suited for use where high accuracy, fast switching, very low power consumption and low intermodulation products are required. Typical applications include dynamic range setting in a precision receiver circuits and other gain/leveling control circuits. Environmental screening is available. Contact the factory for information.

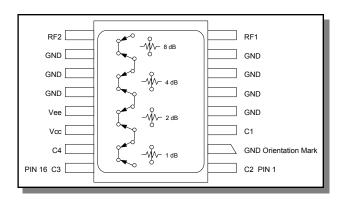
Ordering Information

1

Part Number	Package	
AT-213-PIN	Bulk Packaging	

Note: Reference Application Note M513 for reel size information

Functional Schematic



Pin Configuration

Pin No.	Function	Pin No.	Function
1	C2	9	RF2
2	GND	10	GND
3	C1	11	GND
4	GND	12	GND
5	GND	13	Vee
6	GND	14	Vcc
7	GND	15	C4
8	RF1	16	C3

The metal bottom of the case must be connected to RF and DC ground.

^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

[•] North America Tel: 800.366.2266 • Europe Tel: +353.21.244.6400

India Tel: +91.80.4155721
 China Tel: +86.21.2407.1588
 Visit www.macomtech.com for additional data sheets and product information.

AT-213-PIN



Digital Attenuator 15.0 dB, 4-Bit, TTL Driver, DC-3.0 GHz

Rev. V5

Electrical Specifications: $T_A = -55$ °C to +85°C¹

Parameter	Test Conditions	Frequency	Units	Min	Тур	Max
Reference Insertion Loss	_	DC - 0.5 GHz DC - 1.0 GHz DC - 2.0 GHz DC - 3.0 GHz	dB dB dB dB	_ _ _ _	_ _ _ _	1.7 1.9 2.2 2.5
Attenuation Accuracy ²	Any Single Bit Any Combination of Bits	DC - 2.0 GHz DC - 3.0 GHz DC - 2.0 GHz DC - 3.0 GHz	± (0.15 dB +3% of atten setting in dB) dB ± (0.2 dB +3% of atten setting in dB) dB Or ± 0.4 dB, whichever is greater ± (0.2 dB +3% of atten setting in dB) dB ± (0.2 dB +3% of atten setting in dB) dB Or ± 0.4 dB, whichever is greater			IB) dB ter IB) dB IB) dB
VSWR	_	_	Ratio	_	_	1.6:1
Trise, Tfall	10% to 90%	_	ns	_	9	_
Ton, Toff	50% Control to 90/10% RF	_	ns	_	40	_
Transients	In-Band (peak-peak)	_	mV	_	30	_
1 dB Compression	Input Power Input Power	0.05 GHz 0.5 - 3.0 GHz	dBm dBm	_	+22 +28	_
Input IP3	For two-tone Input Power Up to +5 dBm	0.05 GHz 0.5 - 3.0 GHz	dBm dBm	_	+40 +50	_
Input IP2	For two-tone Input Power Up to +5 dBm	0.05 GHz 0.5 - 3.0 GHz	dBm dBm	_	+45 +68	_
Vcc	_	_	V	4.5	5.0	5.5
Vee	_	_	V	-8.0	_	-5.0
Icc	Vcc = 4.5 to 5.5V Vctl = 0 to 0.8V, or Vcc – 2.1V to Vcc	-	mA	_	_	4.0
lee	Vee = -5.0 to -8.0V	_	mA	_	_	1.0
Vctl Vctl	Logic 0 (TTL) Logic 1 (TTL)		V V	0.0 2.0	_	0.8 5.0
Input Leakage Current (Low)	0 to 0.8V	_	μΑ	_	_	1.0
Input Leakage Current (High)	2.0 to 5.0V	_	μA	_	_	1.0

^{1.} All specifications apply when operated with bias voltages of +5V for Vcc and -5.0V for Vee.

typical. Mechanical outline has been fixed. Engineering samples my Commitment to produce in volume is not guard teed.

^{2.} This attenuator is guaranteed monotonic.

India Tel: +91.80.4155721
 China Tel: +86.21.2407.1588
 Visit www.macomtech.com for additional data sheets and product information.



Digital Attenuator 15.0 dB, 4-Bit, TTL Driver, DC-3.0 GHz

Rev. V5

Absolute Maximum Ratings 3,4

Parameter	Absolute Maximum	
Max Input Power 0.5 GHz 0.5 - 3.0 GHz	+27 dBm +34 dBm	
V _{CC}	-0.5V ≤ V _{CC} ≤ +7.0V	
V _{EE}	-8.5V ≤ V _{EE} ≤ +0.5V	
V _{CC} - V _{EE}	$-0.5V \le V_{CC} - V_{EE} \le 14.5V$	
Vin ⁵	$-0.5V \le Vin \le V_{CC} + 0.5V$	
Operating Temperature	-55°C to +125°C	
Storage Temperature	-65°C to +150°C	

- Exceeding any one or combination of these limits may cause 3 permanent damage to this device.
- M/A-COM does not recommend sustained operation near these survivability limits.
- Standard CMOS TTL interface, latch-up will occur if logic 5. signal is applied prior to power supply.

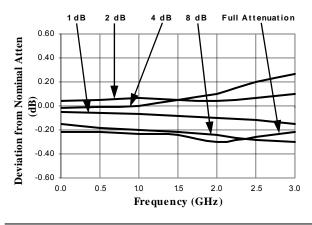
Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Attenuation Accuracy vs. Frequency



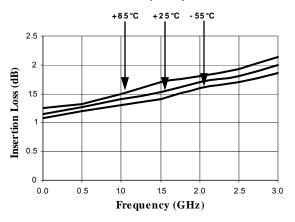
Truth Table (Digital Attenuator)

Control Inputs					
C4	C3	C2	C1	Attenuation	
0	0	0	0	Reference	
0	0	0	1	1 dB	
0	0	1	0	2 dB	
0	1	0	0	4 dB	
1	0	0	0	8 dB	
1	1	1	1	15 dB	

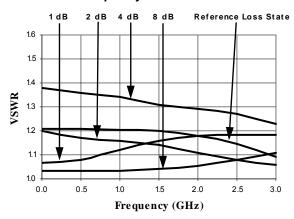
0 = TTL Low; 1 = TTL High

Typical Performance Curves

Ref. Insertion Loss vs. Frequency



RF1 VSWR vs. Frequency



- ADVANCED: Data Sheets contain information regarding a product M/A-COM Technology Solutions is considering for development. Performance is based on target specifications, simulated results, and/or prototype measurements. Commitment to develop is not guaranteed.
- PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are
- North America Tel: 800.366.2266 Europe Tel: +353.21.244.6400 • China Tel: +86.21.2407.1588 • India Tel: +91.80.4155721
 - Visit www.macomtech.com for additional data sheets and product information.

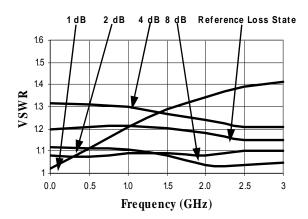


Digital Attenuator 15.0 dB, 4-Bit, TTL Driver, DC-3.0 GHz

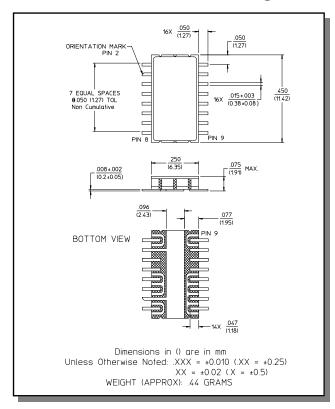
Rev. V5

Typical Performance Curves

RF2 VSWR vs. Frequency



Lead-Free, CR-11 Ceramic Package[†]



[†] Reference Application Note M538 for lead-free solder reflow recommendations.

India Tel: +91.80.4155721
 China Tel: +86.21.2407.1588
 Visit www.macomtech.com for additional data sheets and product information.